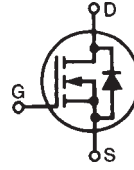


# PolarHV™ HiPerFET Power MOSFET

N-Channel Enhancement Mode  
Avalanche Rated  
Fast Intrinsic Diode

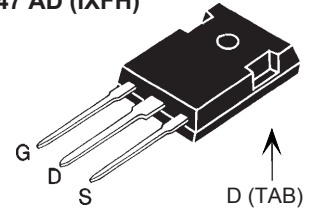
**IXFH 36N50P**  
**IXFT 36N50P**  
**IXFV 36N50P**  
**IXFV 36N50PS**

$V_{DSS} = 500 \text{ V}$   
 $I_{D25} = 36 \text{ A}$   
 $R_{DS(on)} \leq 170 \text{ m}\Omega$   
 $t_{rr} \leq 200 \text{ ms}$

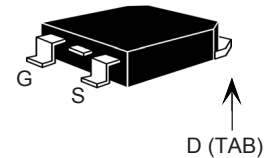


| Symbol     | Test Conditions                                                                                                                         | Maximum Ratings |                  |
|------------|-----------------------------------------------------------------------------------------------------------------------------------------|-----------------|------------------|
| $V_{DSS}$  | $T_J = 25^\circ\text{C to } 175^\circ\text{C}$                                                                                          | 500             | V                |
| $V_{DGR}$  | $T_J = 25^\circ\text{C to } 175^\circ\text{C}; R_{GS} = 1 \text{ M}\Omega$                                                              | 500             | V                |
| $V_{GS}$   | Continuous                                                                                                                              | $\pm 30$        | V                |
| $V_{GSM}$  | Transient                                                                                                                               | $\pm 40$        | V                |
| $I_{D25}$  | $T_C = 25^\circ\text{C}$                                                                                                                | 36              | A                |
| $I_{DM}$   | $T_C = 25^\circ\text{C}$ , pulse width limited by $T_{JM}$                                                                              | 90              | A                |
| $I_{AR}$   | $T_C = 25^\circ\text{C}$                                                                                                                | 36              | A                |
| $E_{AR}$   | $T_C = 25^\circ\text{C}$                                                                                                                | 50              | mJ               |
| $E_{AS}$   | $T_C = 25^\circ\text{C}$                                                                                                                | 1.5             | J                |
| $dv/dt$    | $I_S \leq I_{DM}$ , $di/dt \leq 100 \text{ A}/\mu\text{s}$ , $V_{DD} \leq V_{DSS}$ ,<br>$T_J \leq 150^\circ\text{C}$ , $R_G = 3 \Omega$ | 10              | V/ns             |
| $P_D$      | $T_C = 25^\circ\text{C}$                                                                                                                | 540             | W                |
| $T_J$      |                                                                                                                                         | -55 ... +150    | $^\circ\text{C}$ |
| $T_{JM}$   |                                                                                                                                         | 150             | $^\circ\text{C}$ |
| $T_{stg}$  |                                                                                                                                         | -55 ... +150    | $^\circ\text{C}$ |
| $T_L$      | 1.6 mm (0.062 in.) from case for 10 s                                                                                                   | 300             | $^\circ\text{C}$ |
| $T_{SOLD}$ | Plastic body for 10 s                                                                                                                   | 260             | $^\circ\text{C}$ |
| $M_d$      | Mounting torque (TO-247)                                                                                                                | 1.13/10         | Nm/lb.in.        |
| Weight     | TO-247                                                                                                                                  | 6               | g                |
|            | TO-268                                                                                                                                  | 5               | g                |
|            | PLUS220                                                                                                                                 | 2               | g                |

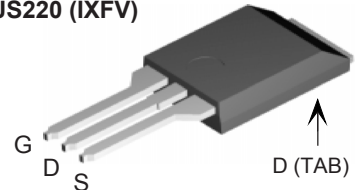
TO-247 AD (IXFH)



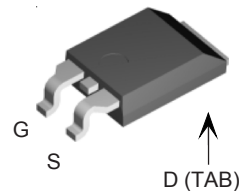
TO-268 (IXFT)



PLUS220 (IXFV)



PLUS220SMD (IXFV...S)



G = Gate  
S = Source

D = Drain  
TAB = Drain

| Symbol       | Test Conditions                                                                                                  | Characteristic Values |      |                                       |
|--------------|------------------------------------------------------------------------------------------------------------------|-----------------------|------|---------------------------------------|
|              |                                                                                                                  | Min.                  | Typ. | Max.                                  |
| $BV_{DSS}$   | $V_{GS} = 0 \text{ V}$ , $I_D = 250 \mu\text{A}$                                                                 | 500                   |      | V                                     |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 4 \text{ mA}$                                                                         | 3.0                   |      | 5.0 V                                 |
| $I_{GSS}$    | $V_{GS} = \pm 30 \text{ V}$ , $V_{DS} = 0$                                                                       |                       |      | $\pm 100 \text{ nA}$                  |
| $I_{DSS}$    | $V_{DS} = V_{DSS}$ , $V_{GS} = 0 \text{ V}$ , $T_J = 125^\circ\text{C}$                                          |                       |      | 25 $\mu\text{A}$<br>500 $\mu\text{A}$ |
| $R_{DS(on)}$ | $V_{GS} = 10 \text{ V}$ , $I_D = 0.5 I_{D25}$<br>Pulse test, $t \leq 300 \mu\text{s}$ , duty cycle $d \leq 2 \%$ |                       |      | 170 m $\Omega$                        |

## Features

- International standard packages
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
- easy to drive and to protect

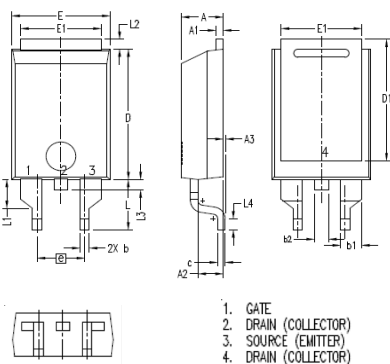
## Advantages

- Easy to mount
- Space savings
- High power density

| Symbol       | Test Conditions                                                                             | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |                        |
|--------------|---------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------|------|------------------------|
|              |                                                                                             | Min.                                                                              | Typ. | Max.                   |
| $g_{fs}$     | $V_{DS} = 20\text{ V}; I_D = 0.5 I_{D25}$ , pulse test                                      | 23                                                                                | 36   | S                      |
| $C_{iss}$    | $V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$                               |                                                                                   | 5500 | pF                     |
| $C_{oss}$    |                                                                                             |                                                                                   | 510  | pF                     |
| $C_{rss}$    |                                                                                             |                                                                                   | 40   | pF                     |
| $t_{d(on)}$  | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 V_{DSS}, I_D = I_{D25}$<br>$R_G = 3\ \Omega$ (External) |                                                                                   | 25   | ns                     |
| $t_r$        |                                                                                             |                                                                                   | 27   | ns                     |
| $t_{d(off)}$ |                                                                                             |                                                                                   | 75   | ns                     |
| $t_f$        |                                                                                             |                                                                                   | 21   | ns                     |
| $Q_{g(on)}$  | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 V_{DSS}, I_D = 0.5 I_{D25}$                             |                                                                                   | 93   | nC                     |
| $Q_{gs}$     |                                                                                             |                                                                                   | 30   | nC                     |
| $Q_{gd}$     |                                                                                             |                                                                                   | 31   | nC                     |
| $R_{thJC}$   |                                                                                             |                                                                                   |      | $0.23^\circ\text{C/W}$ |
| $R_{thCS}$   | (TO-247)                                                                                    | 0.21                                                                              |      | $^\circ\text{C/W}$     |
|              | (PLUS220)                                                                                   | 0.21                                                                              |      | $^\circ\text{C/W}$     |

| Symbol   | Test Conditions                                                                                       | Characteristic Values<br>( $T_J = 25^\circ\text{C}$ , unless otherwise specified) |      |               |
|----------|-------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------|------|---------------|
|          |                                                                                                       | Min.                                                                              | Typ. | Max.          |
| $I_s$    | $V_{GS} = 0\text{ V}$                                                                                 |                                                                                   |      | 36 A          |
| $I_{SM}$ | Repetitive                                                                                            |                                                                                   |      | 90 A          |
| $V_{SD}$ | $I_F = I_s, V_{GS} = 0\text{ V}$ ,<br>Pulse test, $t \leq 300\ \mu\text{s}$ , duty cycle $d \leq 2\%$ |                                                                                   |      | 1.5 V         |
| $t_{rr}$ | $I_F = 25\text{ A}$ ,<br>$-di/dt = 100\text{ A}/\mu\text{s}$<br>$V_R = 100\text{ V}$                  |                                                                                   | 0.8  | 200 ns        |
| $Q_{RM}$ |                                                                                                       |                                                                                   |      | $\mu\text{C}$ |
| $I_{RM}$ |                                                                                                       |                                                                                   |      | A             |

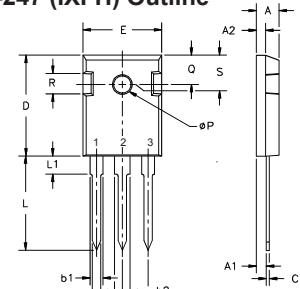
## PLUS220SMD (IXFV\_S) Outline



| SYM | INCHES |          | MILLIMETER |          |
|-----|--------|----------|------------|----------|
|     | MIN    | MAX      | MIN        | MAX      |
| A   | .169   | .185     | 4.30       | 4.70     |
| A1  | .028   | .035     | 0.70       | 0.90     |
| A2  | .098   | .118     | 2.50       | 3.00     |
| A3  | .000   | .010     | 0.00       | 0.25     |
| b   | .035   | .047     | 0.90       | 1.20     |
| b1  | .080   | .095     | 2.03       | 2.41     |
| b2  | .054   | .064     | 1.37       | 1.63     |
| c   | .028   | .035     | 0.70       | 0.90     |
| D   | .551   | .591     | 14.00      | 15.00    |
| D1  | .512   | .539     | 13.00      | 13.70    |
| E   | .394   | .433     | 10.00      | 11.00    |
| E1  | .331   | .346     | 8.40       | 8.80     |
| e   |        | .200 BSC |            | 5.08 BSC |
| L   | .209   | .228     | 5.30       | 5.80     |
| L1  | .118   | .138     | 3.00       | 3.50     |
| L2  | .035   | .051     | 0.90       | 1.30     |
| L3  | .047   | .059     | 1.20       | 1.50     |
| L4  | .039   | .059     | 1.00       | 1.50     |

1. GATE
2. DRAIN (COLLECTOR)
3. SOURCE (EMITTER)
4. DRAIN (COLLECTOR)

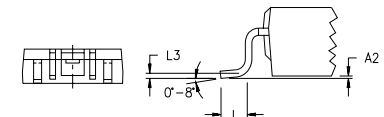
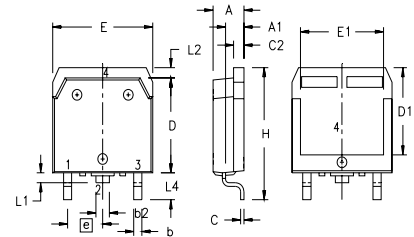
## TO-247 (IXFH) Outline



Terminals: 1 - Gate  
2 - Drain  
3 - Source  
Tab - Drain

| Dim.           | Millimeter |       | Inches |       |
|----------------|------------|-------|--------|-------|
|                | Min.       | Max.  | Min.   | Max.  |
| A              | 4.7        | 5.3   | .185   | .209  |
| A <sub>1</sub> | 2.2        | 2.54  | .087   | .102  |
| A <sub>2</sub> | 2.2        | 2.6   | .059   | .098  |
| b              | 1.0        | 1.4   | .040   | .055  |
| b <sub>1</sub> | 1.65       | 2.13  | .065   | .084  |
| b <sub>2</sub> | 2.87       | 3.12  | .113   | .123  |
| C              | .4         | .8    | .016   | .031  |
| D              | 20.80      | 21.46 | .819   | .845  |
| E              | 15.75      | 16.26 | .610   | .640  |
| e              | 5.20       | 5.72  | 0.205  | 0.225 |
| L              | 19.81      | 20.32 | .780   | .800  |
| L <sub>1</sub> |            | 4.50  |        | .177  |
| ØP             | 3.55       | 3.65  | .140   | .144  |
| Q              | 5.89       | 6.40  | 0.232  | 0.252 |
| R              | 4.32       | 5.49  | .170   | .216  |
| S              | 6.15       | BSC   | 242    | BSC   |

## TO-268 (IXFT) Outline

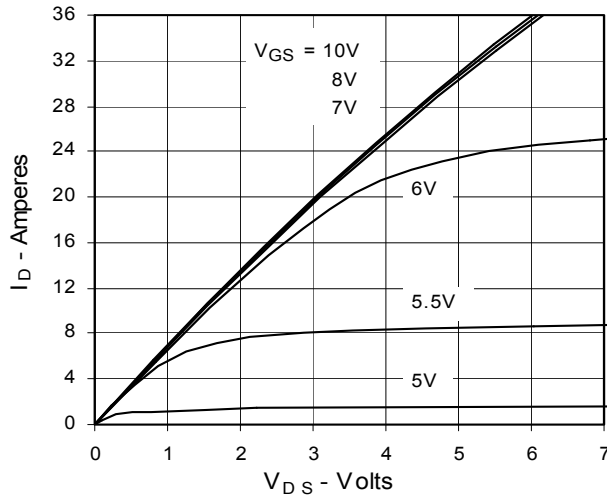


| SYM | INCHES |          | MILLIMETERS |          |
|-----|--------|----------|-------------|----------|
|     | MIN    | MAX      | MIN         | MAX      |
| A   | .193   | .201     | 4.90        | 5.10     |
| A1  | .106   | .114     | 2.70        | 2.90     |
| A2  | .001   | .010     | 0.02        | 0.25     |
| b   | .045   | .057     | 1.15        | 1.45     |
| b2  | .075   | .083     | 1.90        | 2.10     |
| C   | .016   | .026     | 0.40        | 0.65     |
| C2  | .057   | .063     | 1.45        | 1.60     |
| D   | .543   | .551     | 13.80       | 14.00    |
| D1  | .488   | .500     | 12.40       | 12.70    |
| E   | .624   | .632     | 15.85       | 16.05    |
| E1  | .524   | .535     | 13.30       | 13.60    |
| e   |        | .215 BSC |             | 5.45 BSC |
| H   | .736   | .752     | 18.70       | 19.10    |
| L   | .094   | .106     | 2.40        | 2.70     |
| L1  | .047   | .055     | 1.20        | 1.40     |
| L2  | .039   | .045     | 1.00        | 1.15     |
| L3  |        | .010 BSC |             | 0.25 BSC |
| L4  | .150   | .161     | 3.80        | 4.10     |

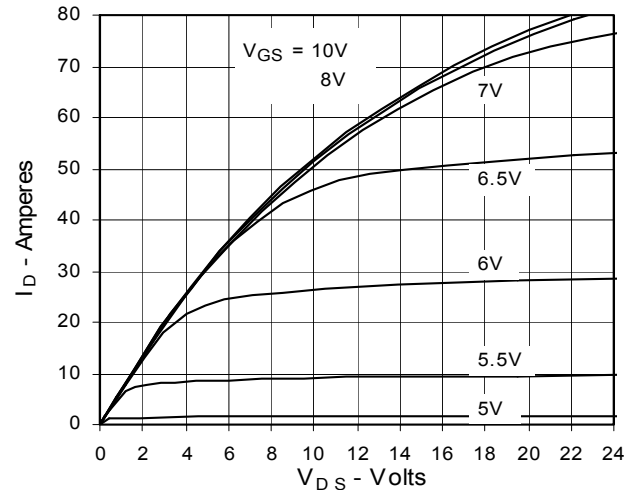
IXYS reserves the right to change limits, test conditions, and dimensions.

IXYS MOSFETs and IGBTs are covered by 4,835,592 4,931,844 5,049,961 5,237,481 6,162,665 6,404,065 B1 6,683,344 6,727,585  
one or more of the following U.S. patents: 4,850,072 5,017,508 5,063,307 5,381,025 6,259,123 B1 6,534,343 6,710,405 B2 6,759,692  
4,881,106 5,034,796 5,187,117 5,486,715 6,306,728 B1 6,583,505 6,710,463 6,771,478 B2

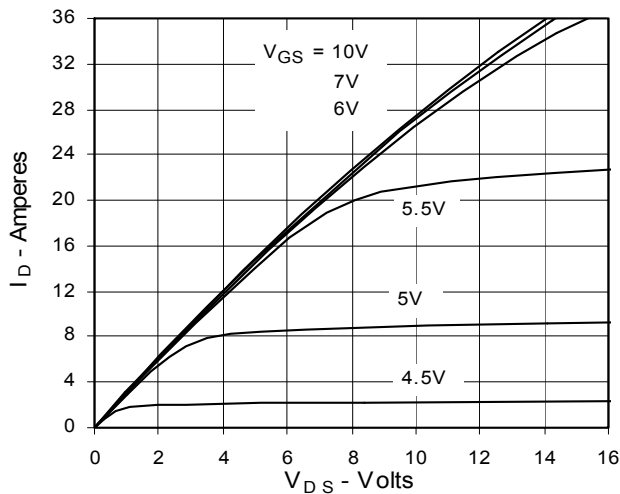
**Fig. 1. Output Characteristics  
@ 25°C**



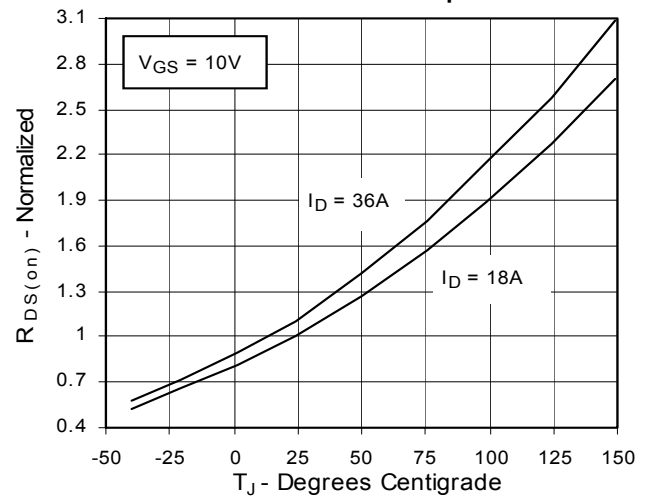
**Fig. 2. Extended Output Characteristics  
@ 25°C**



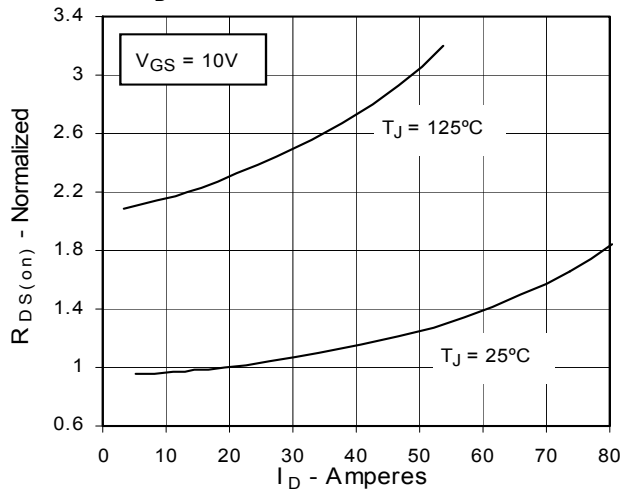
**Fig. 3. Output Characteristics  
@ 125°C**



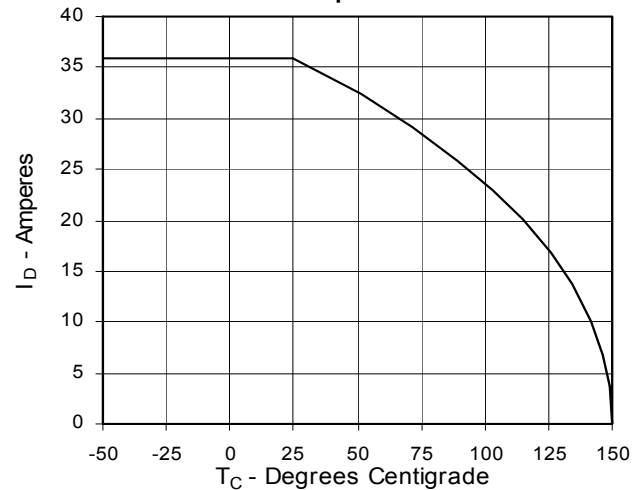
**Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 18A$   
Value vs. Junction Temperature**



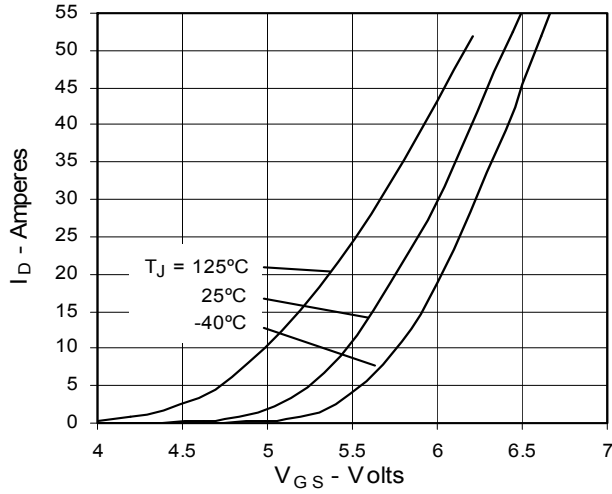
**Fig. 5.  $R_{DS(on)}$  Normalized to  
 $I_D = 18A$  Value vs. Drain Current**



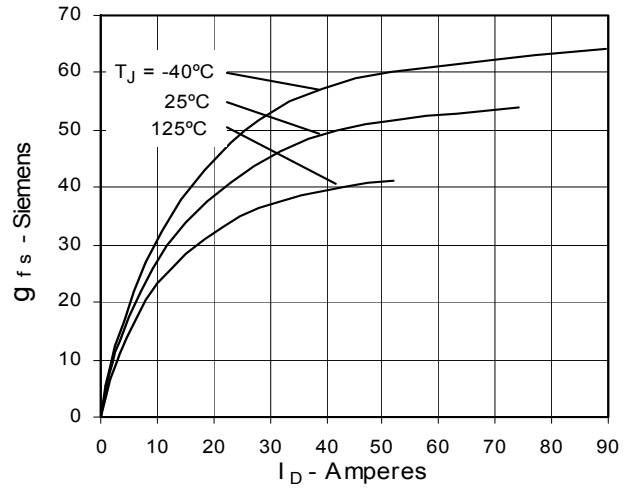
**Fig. 6. Drain Current vs. Case  
Temperature**



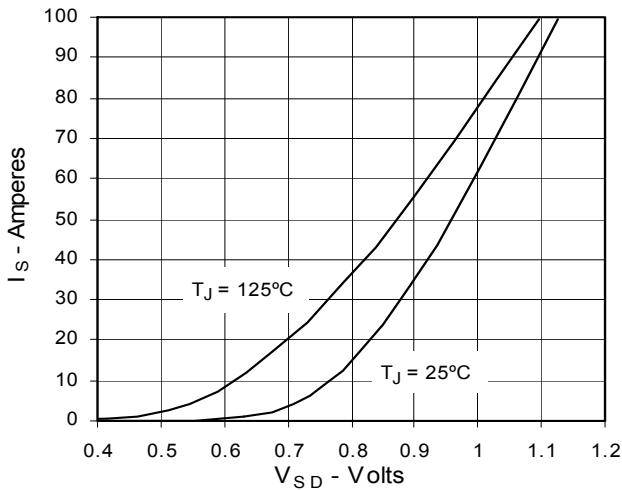
**Fig. 7. Input Admittance**



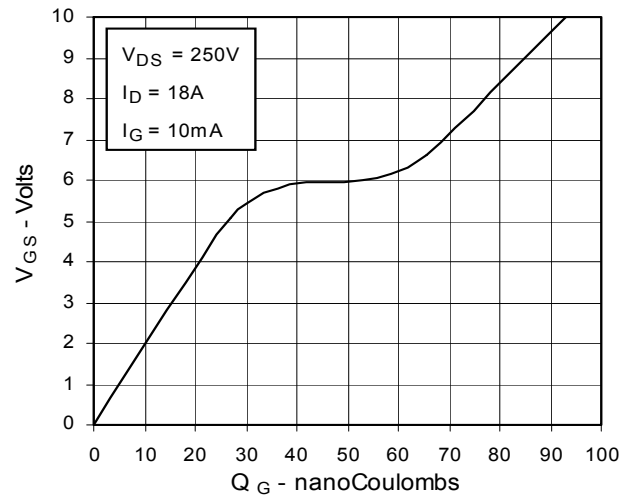
**Fig. 8. Transconductance**



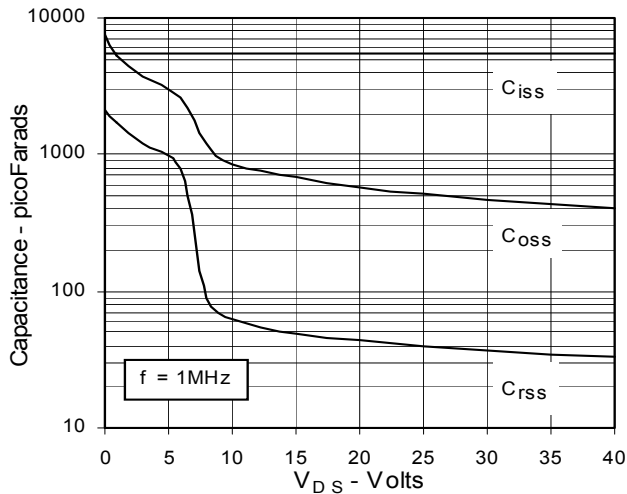
**Fig. 9. Source Current vs. Source-To-Drain Voltage**



**Fig. 10. Gate Charge**



**Fig. 11. Capacitance**



**Fig. 12. Forward-Bias Safe Operating Area**

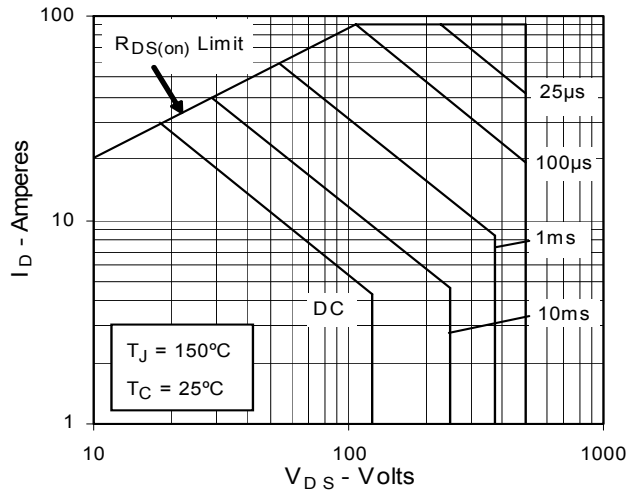
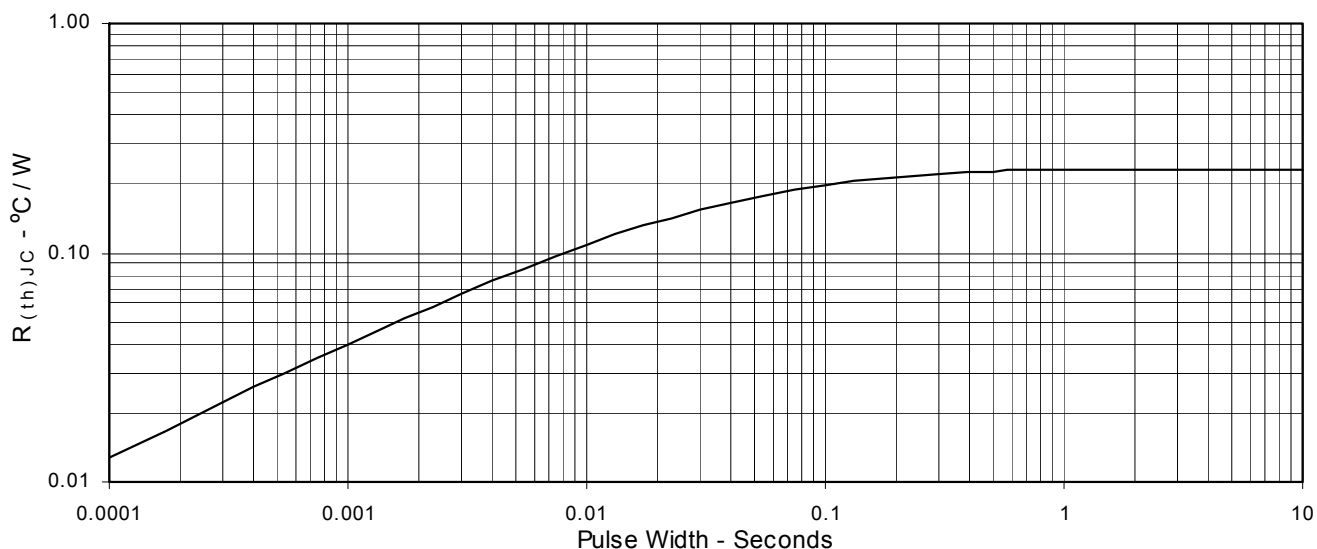
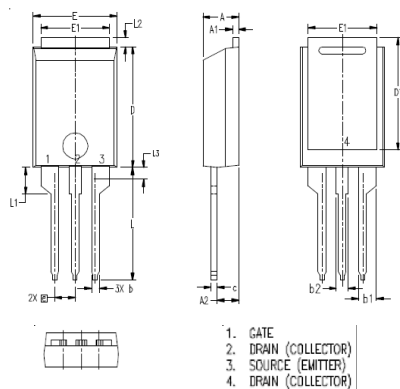


Fig. 13. Maximum Transient Thermal Resistance



PLUS220 (IXFV) Outline



| SYM | INCHES   |      | MILLIMETER |       |
|-----|----------|------|------------|-------|
|     | MIN      | MAX  | MIN        | MAX   |
| A   | .169     | .185 | 4.30       | 4.70  |
| A1  | .028     | .035 | 0.70       | 0.90  |
| A2  | .098     | .118 | 2.50       | 3.00  |
| b   | .035     | .047 | 0.90       | 1.20  |
| b1  | .080     | .095 | 2.03       | 2.41  |
| b2  | .054     | .064 | 1.37       | 1.63  |
| c   | .028     | .035 | 0.70       | 0.90  |
| D   | .551     | .591 | 14.00      | 15.00 |
| D1  | .512     | .539 | 13.00      | 13.70 |
| E   | .394     | .433 | 10.00      | 11.00 |
| E1  | .331     | .346 | 8.40       | 8.80  |
| e   | .100 BSC |      | 2.54 BSC   |       |
| L   | .512     | .551 | 13.00      | 14.00 |
| L1  | .118     | .138 | 3.00       | 3.50  |
| L2  | .035     | .051 | 0.90       | 1.30  |
| L3  | .047     | .059 | 1.20       | 1.50  |